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ON Semiconductor® FDMS86580-F085

N-Channel PowerTrench[®] MOSFET

60 V, 50 A, 9.6 mΩ

Features

- Typical $R_{DS(on)}$ = 7.9 m Ω at V_{GS} = 10V, I_D = 50 A
- Typical Q_{g(tot)} = 20 nC at V_{GS} = 10V, I_D = 50 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter/Alternator
- Distributed Power Architectures and VRM
- Primary Switch for 12V Systems

MOSFET Maximum Ratings T_J = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		60	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
I _D	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	50	Α	
	Pulsed Drain Current	$T_C = 25^{\circ}C$	See Figure 4	A	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	19	mJ	
P _D	Power Dissipation		75	W	
	Derate Above 25°C		0.5	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		2.0	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	50	°C/W	

Notes:

- 1: Current is limited by bondwire configuration.

ROHS

2: Starting T_J = 25°C, L = 20µH, I_{AS} = 44A, V_{DD} = 60V during inductor charging and V_{DD} = 0V during time in avalanche. 3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

Device Marking	Device	Package Reel Size		Tape Width	Quantity		
FDMS86580	FDMS86580-F085	Power 56	13"	12mm	3000units		

Bottom

D

D

S S

S G

Тор

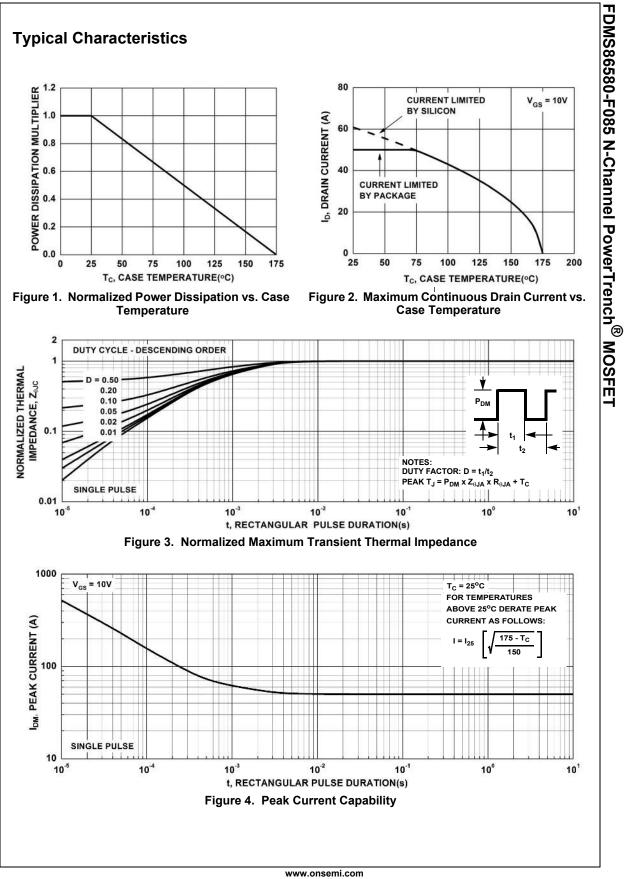
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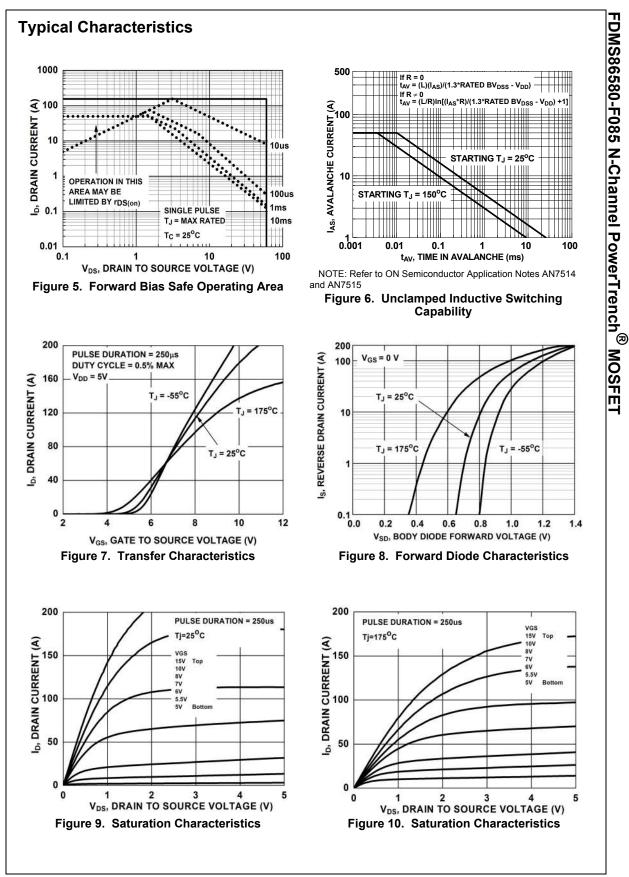
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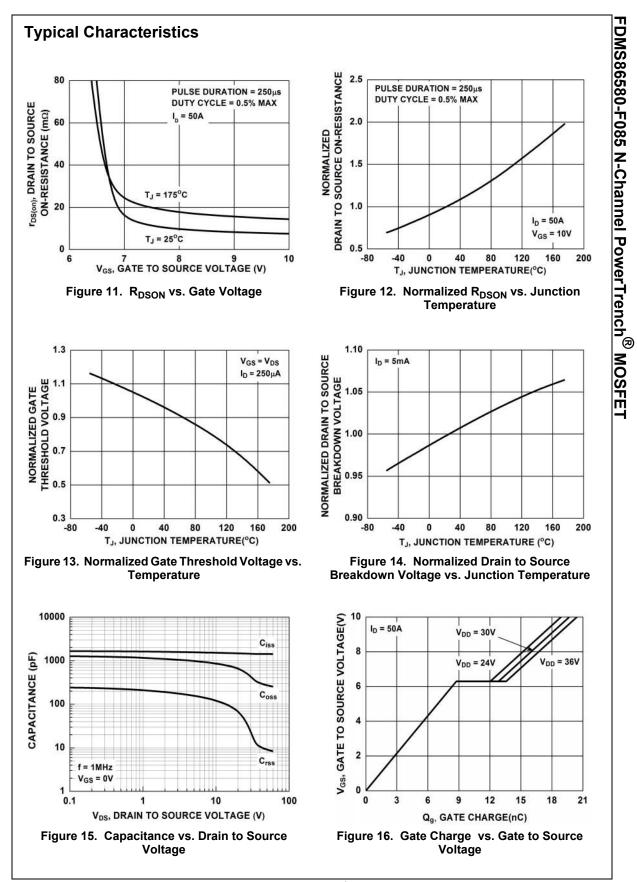
Symbol	Parameter	Test Conditions			Min.	Тур.	Max.	Units
Off Cha	racteristics							
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA,	V _{GS} = ()V	60	-	-	V
	Drain-to-Source Leakage Current	V_{DS} =60V, T_{J} =25°C			-	-	1	μA
IDSS				75 ^o C (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	V _{GS} = ±20V		-	-	±100	nA	
On Cha	racteristics							
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA		2.0	3.5	4.2	V	
_	Drain to Source On Resistance	$I_{\rm D} = 50$ A, $T_{\rm J} = 25^{\circ}$ C			-	7.9	9.6	mΩ
R _{DS(on)}		V _{GS} = 10V	т _ј =	175°C (Note 4)	-	15.6	19.5	mΩ
-	c Characteristics			1				
C _{iss}	Input Capacitance	V _{DS} = 30V, V _{GS} = 0V, f = 1MHz		-	1430	-	pF	
C _{oss}	Output Capacitance			-	440	-	pF	
C _{rss}	Reverse Transfer Capacitance			-	25	-	pF	
R _g	Gate Resistance	V _{GS} = 0.5V, f = 1MHz		-	1.8	-	Ω	
Q _{g(ToT)}	Total Gate Charge	$V_{GS} = 0$ to 10V $V_{DD} = 30V$		V _{DD} = 30V	-	20	30	nC
Q _{g(th)}	Threshold Gate Charge	V _{GS} = 0 to 2	V	I _D = 50A	-	3	-	nC
Q _{gs}	Gate-to-Source Gate Charge			-	-	9	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge				-	4	-	nC
Switchi	ng Characteristics							
t _{on}	Turn-On Time				-	-	30	ns
t _{d(on)}	Turn-On Delay	V_{DD} = 30V, I _D = 50A, V _{GS} = 10V, R _{GEN} = 6Ω		-	13	-	ns	
t _r	Rise Time			-	7	-	ns	
t _{d(off)}	Turn-Off Delay			-	15	-	ns	
t _f	Fall Time			-	5	-	ns	
t _{off}	Turn-Off Time			-	-	30	ns	
Drain-S	ource Diode Characteristics							
\/	Source-to-Drain Diode Voltage	I _{SD} = 50A, V _{GS} = 0V		V	-	0.97	1.3	V
V_{SD}	Source-to-Drain Diode Voltage	I _{SD} = 25A, V _{GS} = 0V			-	0.88	1.2	V
t _{rr}	Reverse-Recovery Time	V_{DD} = 48V, I _F = 50A, dI _{SD} /dt = 100A/µs		-	44	66	ns	
Q _{rr}	Reverse-Recovery Charge			-	28	42	nC	







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